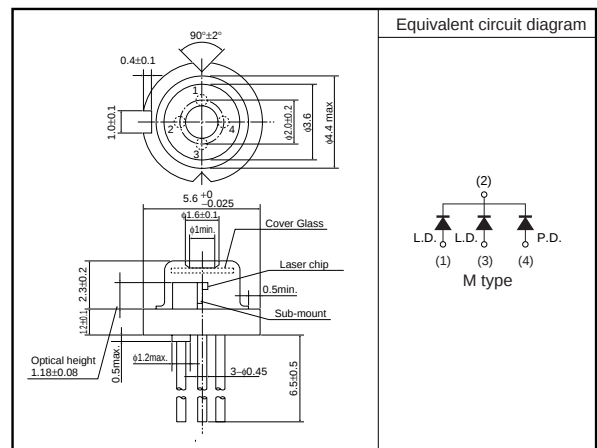


RLD2WMNV1

●Applications

●External dimensions (Units : mm)

- 1) Optimization of a strained multi quantum well realizes the reduction in threshold current, and the good temperature characteristic.
- 2) Low threshold current.
785nm : 18mA ($T_c=25^{\circ}\text{C}$)
655nm : 20mA ($T_c=25^{\circ}\text{C}$)
- 3) Low noise is realized by high frequency modulation (BU9369FVM)element.
- 4) Emission point distance : 110 μm



785mm

Parameter		Symbol	Limits	Unit
Output		P _O	7	mW
Reverse voltage	Laser	V _R	2	V
	PIN photodiode	V _{R(PIN)}	30	V
Operating temperature		T _{opr}	−10 to +70	°C
Storage temperature		T _{stg}	−40 to +85	°C

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Reverse voltage	Laser	V _R	2	V
	PIN photodiode	V _{R(PIN)}	30	V
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Laser Diodes

●Electrical and optical characteristics (T_c=25°C)

785nm

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Threshold current	I _{th}	–	18	50	mA	–
Operating current	I _{op}	–	30	60	mA	P _o =5mW
Operating voltage	V _{op}	–	1.9	2.3	V	P _o =5mW
Differential efficiency	η	0.1	0.4	0.6	mW/mA	–
Monitor current	I _m	0.15	0.25	0.65	mA	P _o =5mW
Parallel divergenc angle	θ _∥ *	7	10	15	deg	P _o =5mW
Perpendicular divergence angle	θ _⊥ *	25	32	39	deg	P _o =5mW
Parallel deviation angle	Δθ _∥	–2	0	+2	deg	P _o =5mW
Perpendicular deviation angle	Δθ _⊥	–3	0	+3	deg	P _o =5mW
Emission point accuracy	$\frac{\Delta X}{\Delta Y}$ ΔZ	–80	0	+80	μm	–
Peak emission wavelength	λ	770	785	810	nm	P _o =5mW
Astigmatism	Δℓ	–	–	10	μm	P _o =5mW

* θ_∥ and θ_⊥ are defined as the angle within which the intensity is 50% of the peak value.

655nm

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Threshold current	I _{th}	–	20	50	mA	–
Operating current	I _{op}	–	28	60	mA	P _o =5mW
Operating voltage	V _{op}	–	2.3	2.7	V	P _o =5mW
Differential efficiency	η	0.4	0.7	1.0	mW/mA	–
Monitor current	I _m	0.1	0.14	0.4	mA	P _o =5mW
Parallel divergenc angle	θ _∥ *	7	8	10	deg	P _o =5mW
Perpendicular divergence angle	θ _⊥ *	20	27	35	deg	P _o =5mW
Parallel deviation angle	Δθ _∥	–2	0	+2	deg	P _o =5mW
Perpendicular deviation angle	Δθ _⊥	–3	0	+3	deg	P _o =5mW
Peak emission wavelength	λ	645	655	660	nm	P _o =5mW
Astigmatism	Δℓ	–	–	10	μm	P _o =5mW

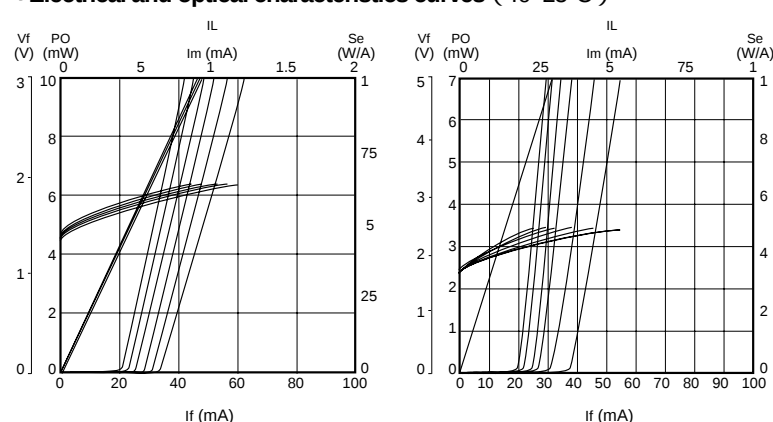
* θ_∥ and θ_⊥ are defined as the angle within which the intensity is 50% of the peak value.●Electrical and optical characteristics curves (T_c=25°C)

Fig.1 785nm Optical output vs. operating current

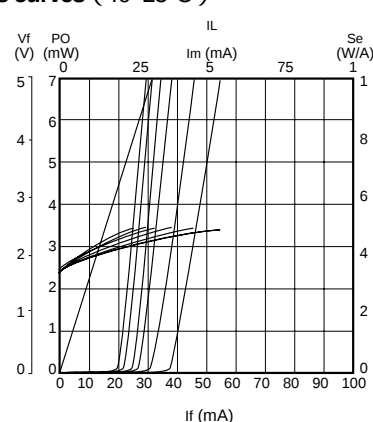


Fig.2 655nm Optical output vs. operating current

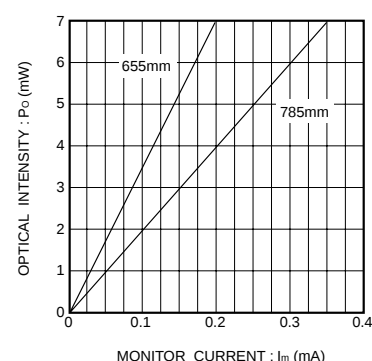


Fig.3 Monitor current vs. optical output